

An IATF 16949, ISO9001 and ISO 14001 Certified Company

High Power NPN Silicon Power Transistors

20 AMPERES, 90 VOLTS, 140 WATTS





TO-3 Metal Can Package RoHS compliant



TO-3

FEATURES: Fast switching speeds and high current capacity

High Speed - $t_f = 0.5s$ (Max)

High Current - I_C=30Amp

Low Saturation - $V_{CE(sat)}$ = 2.5 V (Max) @ I_C = 20Amp

APPLICATIONS: Switching regulators, inverters, wide–band amplifiers and power oscillators in industrial and commercial applications.

ABSOLUTE MAXIMUM RATINGS $(T_a = 25 \, ^{\circ}C)$

Rating	Symbol	Value	Unit
Collector–Base Voltage	V _{CBO}	150	Vdc
Collector–Emitter Voltage	V _{CEV}	150	Vdc
Emitter-Base Voltage	V _{EBO}	7	Vdc
Collector Current - Continuous Peak (1)	I _C	20 30	Adc
Base Current – Continuous	I _B	5	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	140 0.8	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{JC}	1.25	°C/W

*Indicates JEDEC Registered Data.

(1) Pulse Test: Pulse Width \leq 10 ms, Duty Cycle \leq 50%.

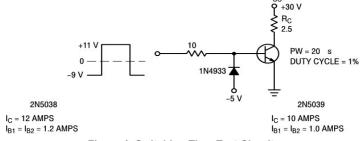


Figure 1. Switching Time Test Circuit



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ELECTRICAL CHARACTERISTICS (T_A=25 ° C unless otherwise specified)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERIS	TICS				
Collector–Emitter Sustaining Voltage (2) (I _C = 200 mAdc, I _B = 0)		V _{CEO(sus)}	90	_	Vdc
Collector Cutoff Curr (V _{CE} = 140 Vdc, V (V _{CE} = 100 Vdc, V	ICEX		50 10	mAdc	
Emitter Cutoff Curre (V _{EB} = 5 Vdc, I _C = (V _{EB} = 7 Vdc, I _C =	= 0)	I _{EBO}	1	5 50	mAdc
ON CHARACTERIST	TICS (2)				
DC Current Gain (I _C = 12 Adc, V _{CE} = 5 Vdc)		h _{FE}	20	100	-
Collector–Emitter Sa (I _C = 20 Adc, I _B =	3	V _{CE(sat)}		2.5	Vdc
Base–Emitter Satura (I _C = 20 Adc, I _B =		V _{BE(sat)}	-	3.3	Vdc
OYNAMIC CHARACT	FERISTICS	22	di.		
Magnitude of Common–Emitter Small–Signal Short–Circuit Forward Current Transfer Ratio (I _C = 2 Adc, V _{CE} = 10 Vdc, f = 5 MHz)		h _{fe}	12	-	-
SWITCHING CHARA	CTERISTICS				
RESISTIVE LOAD		(59)	.,,		
Rise Time	(V _{CC} = 30 Vdc)	t _r	_	0.5	s
Storage Time	(I _C = 12 Adc, I _{B1} = I _{B2} = 1.2 Adc)	t _s	_	1.5	s

^{*}Indicates JEDEC Registered Data.

⁽²⁾ Pulse Test: Pulse Width ≤ 300, s, Duty Cycle ≤ 2%.

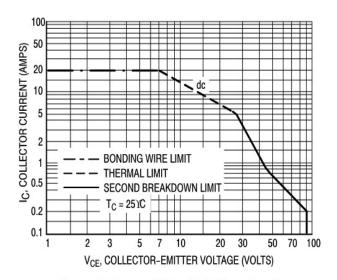


Figure 2. Forward Bias Safe Operating Area

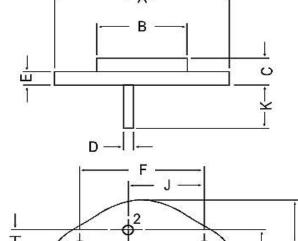






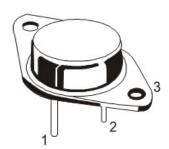


Package Details



	mm.
	⊆
	dimensions
:	7

DIM	MIN.	MAX.
Α		39.37
В	_	22.22
С	6.35	8.50
D	0.96	1.09
E	1	1.77
F	29.90	30.40
G	10.69	11.18
Н	5.20	5.72
J	16.64	17.15
K	11.15	12.25
L		26.67
М	3.84	4.19



G

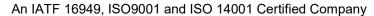
PIN CONFIGURATION

- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

Packing Detail

PACKAGE	STAND	ARD PACK	INNER CARTO	ON BOX	OUTER	CARTON BOX	
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs









Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level				
Level	Time	Condition		
1	Unlimited	≤30 °C / 85% RH		
2	1 Year	≤30 °C / 60% RH		
2a	4 Weeks	≤30 °C / 60% RH		
3	168 Hours	≤30 °C / 60% RH		
4	72 Hours	≤30 °C / 60% RH		
5	48 Hours	≤30 °C / 60% RH		
5a	24 Hours	≤30 °C / 60% RH		
6	Time on Label(TOL)	≤30 °C / 60% RH		







Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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2N5769 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E

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